





N-CHANNEL ENHANCEMENT MODE MOSFET

Features

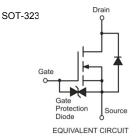
- Low On-Resistance
- Very Low Gate Threshold Voltage (1.0V max)
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

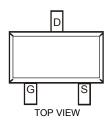
Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe.
 Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (approximate)









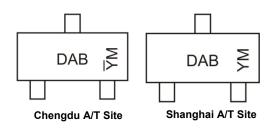
Ordering Information (Note 4)

Ī	Part Number	Case	Packaging
	DMN5L06WK-7	SOT-323	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



DAB = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) \overline{Y} M = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Year	2012	2	2013		2014	20	15	2016		2017		2018
Code	Z		Α		В	(0	D		Е		F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

	Characteristic	Symbol	Value	Unit
Drain Source Voltage		V_{DSS}	50	V
Gate-Source Voltage		V_{GSS}	±20	V
Drain Current (Note 5)	Continuous	I _D	300	mA
	Pulsed (Note 6)	_	800	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	250	mW
Thermal Resistance, Junction to Ambient	R _{0JA}	500	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

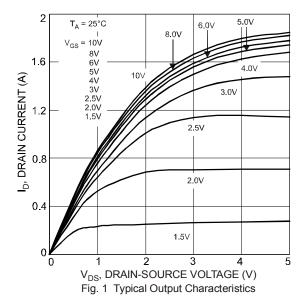
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

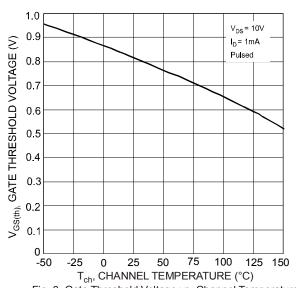
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)		Symbol	IVIIII	iyp	IVIAA	Oilit	rest condition	
Drain-Source Breakdown Voltage		BV _{DSS}	50	_	_	V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current	@T _C = +25°C	I _{DSS}	_	_	60	nA	V _{DS} = 50V, V _{GS} = 0V	
					1	μΑ	$V_{GS} = \pm 12V, V_{DS} = 0V$	
Gate-Body Leakage		I_{GSS}	_		500	nA	$V_{GS} = \pm 10V$, $V_{DS} = 0V$	
					50	nA	$V_{GS} = \pm 5V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage		V _{GS(th)}	0.49	—	1.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		R _{DS (ON)}	_	_	3.0	Ω	$V_{GS} = 1.8V, I_D = 50mA$	
Static Drain-Source On-Resistance			_	_	2.5		$V_{GS} = 2.5V, I_D = 50mA$	
			_	_	2.0		$V_{GS} = 5.0V, I_D = 50mA$	
On-State Drain Current		I _{D(ON)}	0.5	1.4	_	Α	$V_{GS} = 10V, V_{DS} = 7.5V$	
Forward Transconductance		Y _{fs}	200	_	_	mS	V_{DS} =10V, I_{D} = 0.2A	
Source-Drain Diode Forward Voltage		V_{SD}	0.5	_	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$	
DYNAMIC CHARACTERISTICS (Note 8)		•				•		
Input Capacitance		C _{iss}	_	_	50	pF	V 05V V 0V	
Output Capacitance		Coss	_	_	25	pF	V _{DS} = 25V, V _{GS} = 0V -f = 1.0MHz	
Reverse Transfer Capacitance		Crss	_	_	5.0	pF T= 1.0MH2		
Turn-On Delay Time		$t_{D(on)}$	_	2.1		ns		
Turn-On Rise Time			_	1.8	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time		t _{D(off)}	_	14.4		ns	$R_G = 25\Omega, I_D = 200 \text{mA}$	
Turn-Off Fall Time		t _f	_	8.4		ns		

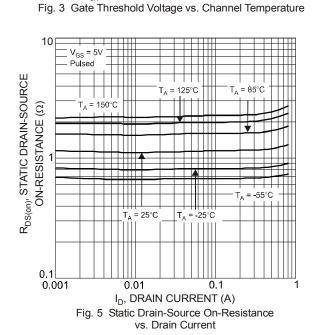
- Notes: 5. Device mounted on FR-4 PCB.

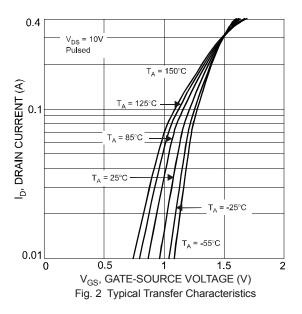
 - Pulse width ≤10µS, Duty Cycle ≤1%.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.











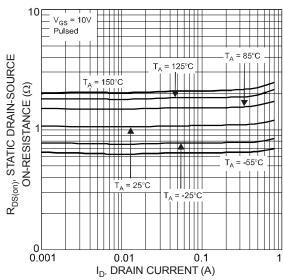
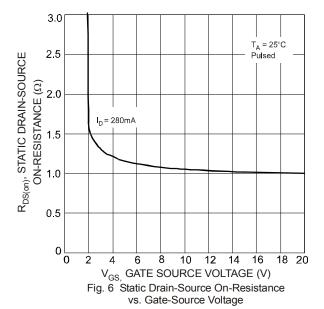


Fig. 4 Static Drain-Source On-Resistance vs. Drain Current





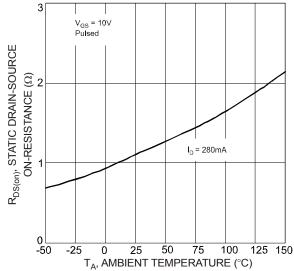


Fig. 7 Static Drain-Source On-State Resistance vs. Ambient Temperature

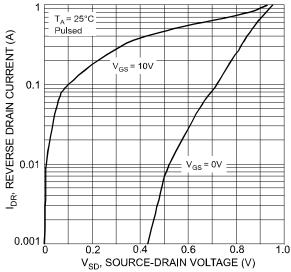
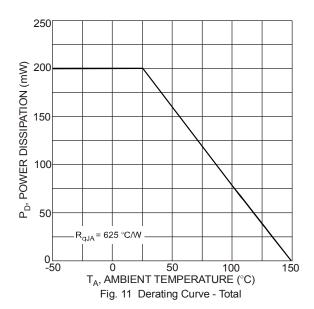


Fig. 9 Reverse Drain Current vs. Source-Drain Voltage



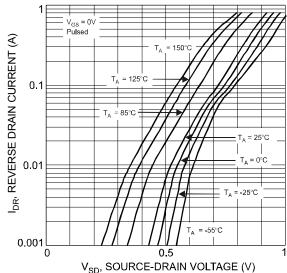


Fig. 8 Reverse Drain Current vs. Source-Drain Voltage

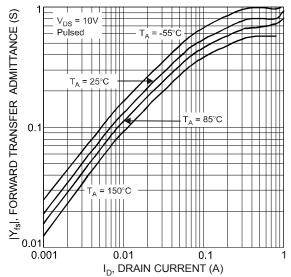
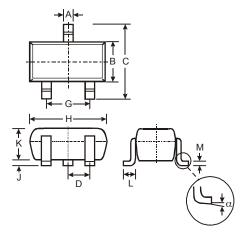


Fig. 10 Forward Transfer Admittance vs. Drain Current



Package Outline Dimensions

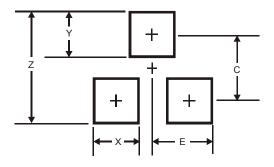
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT-323								
Dim	Min	Max	Тур					
Α	0.25	0.40	0.30					
В	1.15	1.35	1.30					
С	2.00	2.20	2.10					
D	-	-	0.65					
G	G 1.20		1.30					
Н	1.80	2.20	2.15					
J	J 0.0		0.05					
K	0.90	1.00	0.95					
L	0.25	0.40	0.30					
M	M 0.10		0.11					
α	0°	8°	-					
All	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
X	0.7
Y	0.9
С	1.9
E	1.0



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